



#### **DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR**

## **Features**

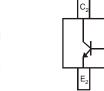
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT4126)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Notes 5 and 6)

## **Mechanical Data**

- Case: SOT-363
- Case Material: Molded Plastic, "Green" Molding Compound, Note 6. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3

**Device Schematic** 

- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)





Top View

### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	30	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Collector Current – Continuous (Note 1)	lc	200	mA

#### Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation	(Notes 1 & 2)	$P_D$	200	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ hetaJA}$	625	°C/W
Operating and Storage and Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

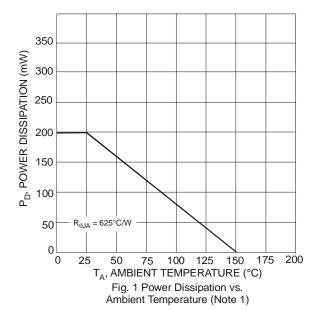
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

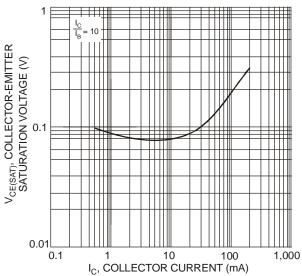
Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 4)					
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	30		V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	25		V	$I_C = 1.0 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5.0		V	$I_E = 10 \mu A, I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>		50	nA	$V_{CB} = 20V, I_E = 0V$
Emitter Cutoff Current	I <sub>EBO</sub>		50	nA	$V_{EB} = 3.0V, I_{C} = 0V$
ON CHARACTERISTICS (Note 4)					
DC Current Gain	h	120	360		$I_C = 2.0 \text{mA}, V_{CE} = 1.0 \text{V}$
DC Current Gain	h <sub>FE</sub>	60			$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.30	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>		0.95	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	$C_{obo}$	_	4.0	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$
Input Capacitance	C <sub>ibo</sub>		8.0	pF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_C = 0$
Small Signal Current Gain	h <sub>fe</sub>	120	480	_	$V_{CE} = 1.0V, I_{C} = 2.0mA, f = 1.0kHz$
Current Gain-Bandwidth Product	f⊤	300		MHz	V <sub>CE</sub> = 20V, I <sub>C</sub> = 10mA, f = 100MHz
Noise Figure	NF	·	5.0	dB	$V_{CE} = 5.0V$ , $I_C = 100\mu A$ ,
Noise rigule	INF	_	5.0	ub	$R_S = 1.0k\Omega$ , $f = 1.0kHz$

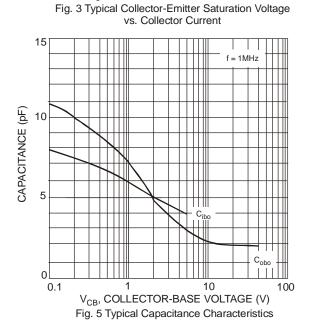
Notes:

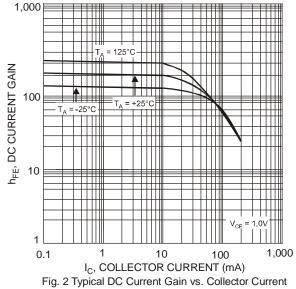
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. Maximum combined dissipation.
- 3. No purposefully added lead.
- Short duration pulse test used to minimize self-heating effect.
- 5. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 6. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.











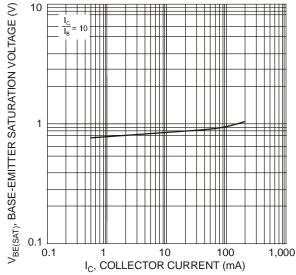


Fig. 4 Typical Base-Emitter Saturation Voltage vs. Collector Current

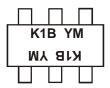


## Ordering Information (Note 5)

Part Number	Case	Packaging
MMDT4124-7-F	SOT-363	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



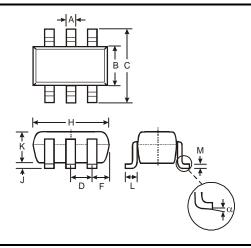
K1B = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Date Code Kev

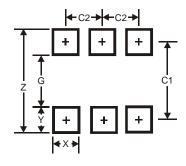
_	Date Code No	y																	
	Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
	Code	J	K	L	M	Ν	Р	R	S	Т	J	>	W	Χ	Υ	Z	Α	В	С
_																			
	Month	Jan		Feb	Maı	r	Apr	May	/	Jun	Jul	l .	Aug	Sep		Oct	Nov	,	Dec
Γ	Code	1		2	3		4	5		6	7		8	9		0	N		D

## **Package Outline Dimensions**



SOT-363							
Dim	Min	Max					
Α	0.10	0.30					
В	1.15	1.35					
C	2.00	2.20					
D	0.65	Тур					
F	0.40 0.45						
Н	1.80 2.20						
7	0 0.10						
K	0.90	1.00					
L	0.25	0.40					
М	0.10 0.22						
α	α 0° 8°						
All Di	All Dimensions in mm						

## **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65

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